Application of Genetic Algorithm Parameter Optimization on I-V data of multi-crystalline Si solar cells

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an introduction to Artemis

Outcomes

Introduce the concept of Genetic Algorithms for Parameter Optimisation

Custom built Genetic Algorithm for the purpose of:

Characterisation of Current-Voltage data the forward bias

Outline

Introduction to Genetic Algorithms

Genetic Algorithm Structure and Implementation

Initialization

Fitness Evaluation

Selection Process

Genetic Crossover

Genetic Mutation

Termination Conditions

Applied models

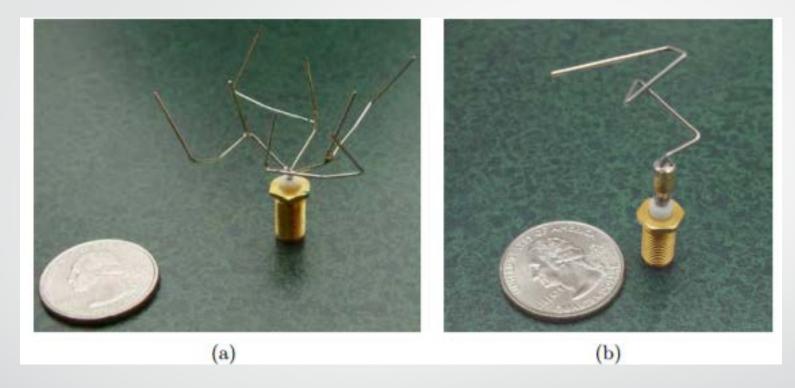
Implementation of code

Results obtained

Future applications

Conclusions

Example



- (a) Best evolved design for antenna for original requirements ST5-3-10
- (b) Best evolved design for antenna for revised requirements ST5-33-142-7

"The 2006 NASA ST5 spacecraft antenna. This complicated shape was found by an evolutionary computer design program to create the best radiation pattern."

Source: Hornby, Gregory S.; Al Globus; Derek S. Linden; Jason D. Lohn (September 2006). "Automated antenna design with evolutionary algorithms" (PDF). American Institute of Aeronautics and Astronautics. Retrieved 2012-02-19.



Introduction to Genetic Algorithms

Evolutionary algorithm

Based upon the biological process of evolution of genetic material

Pro's:

Parallel interacting solutions

Increased probability of finding global minimum of error (compared to classical approaches)

Customization for case-specific problems

Con's:

Computationally expensive

Unsuitable for simple problems

Partitioning of data

Training set

Validation set

Introduction: Terminology

Training Set

The set of data used to train the model to the data (determine parameter values)

Validation Set

The set of data used to validate the optimized parameter values for the applied model

Test of over specification

Genes

In the case of this GA, the parameter values for the model

Individuals

The set of parameters of a proposed solution



Introduction: Terminology

Fitness Function

The function used to test the fitness of an individual, or how well the applied parameter values perform

Diversity

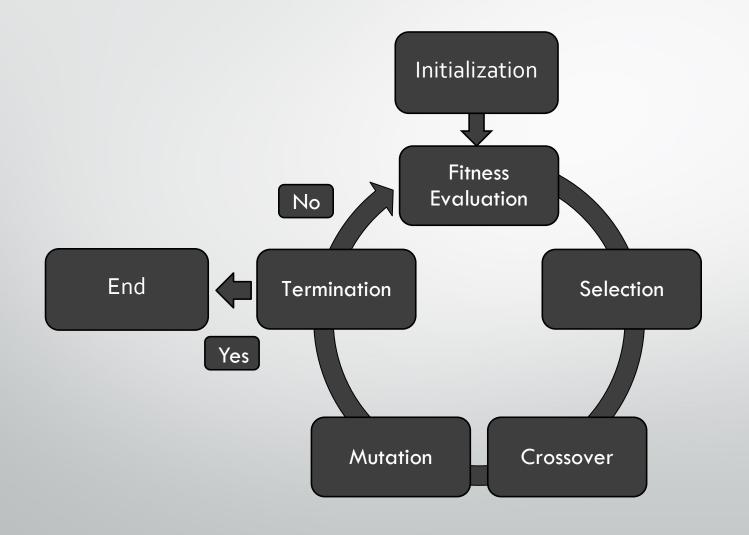
The variety of the population's parameters

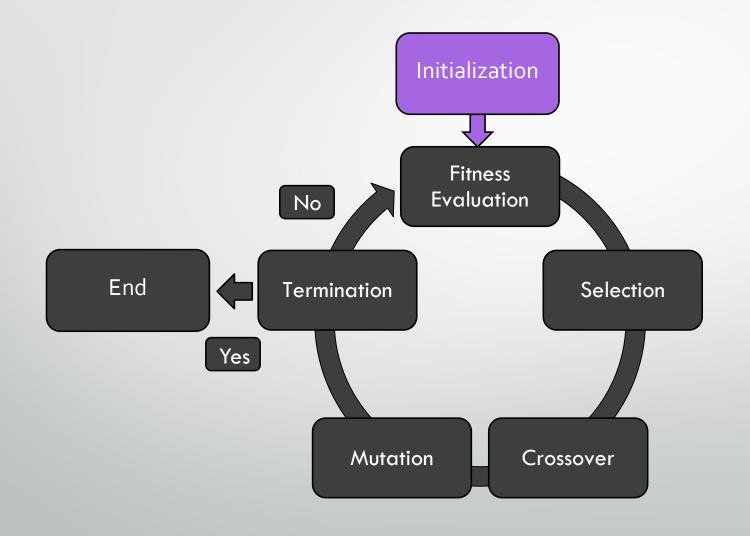
Breeding Set

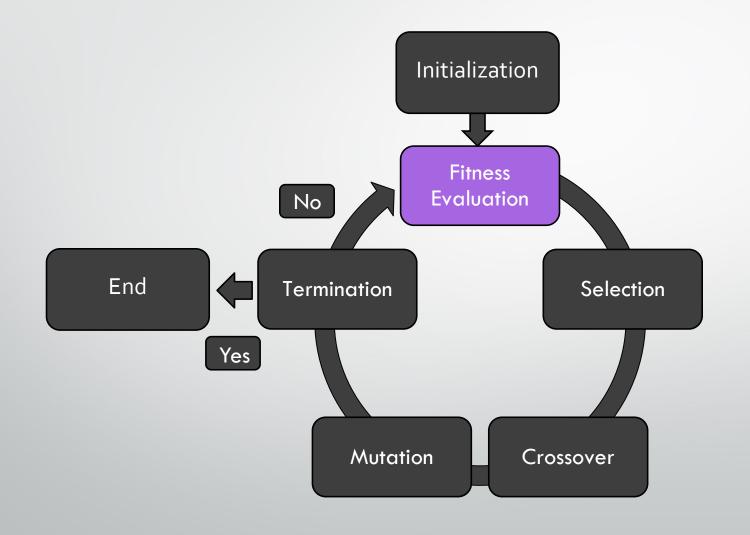
The set used in the crossover process to generate the new generation

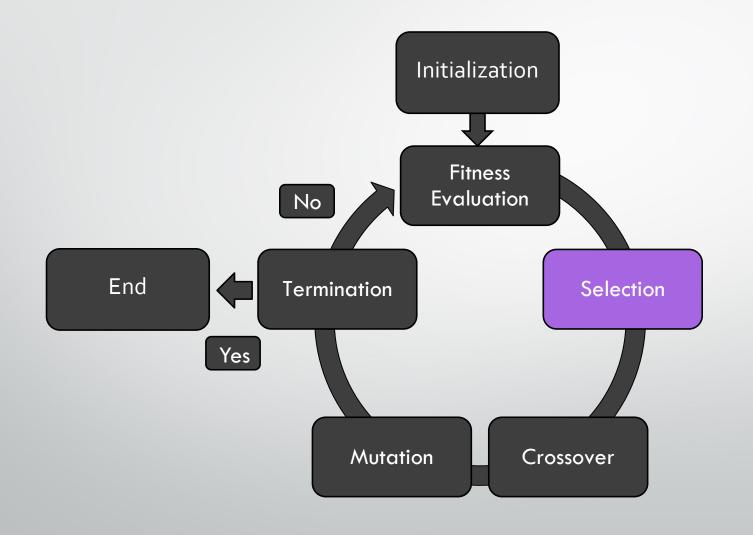
New Generation

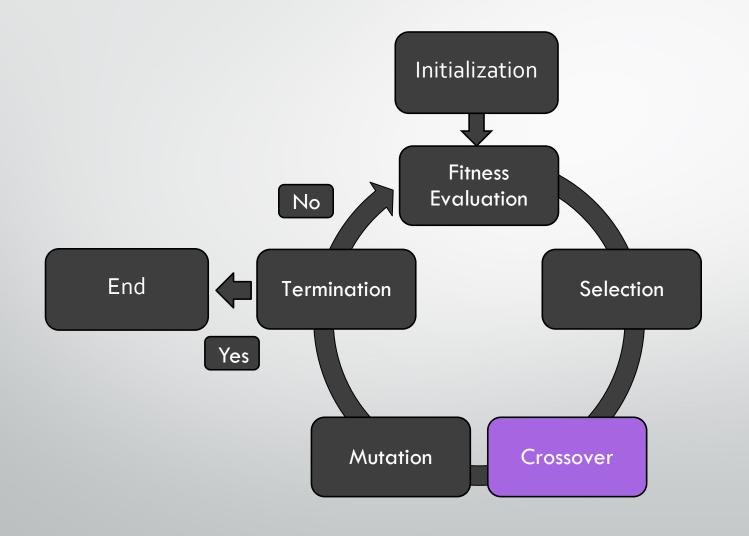
The set used in the next iteration of the GA

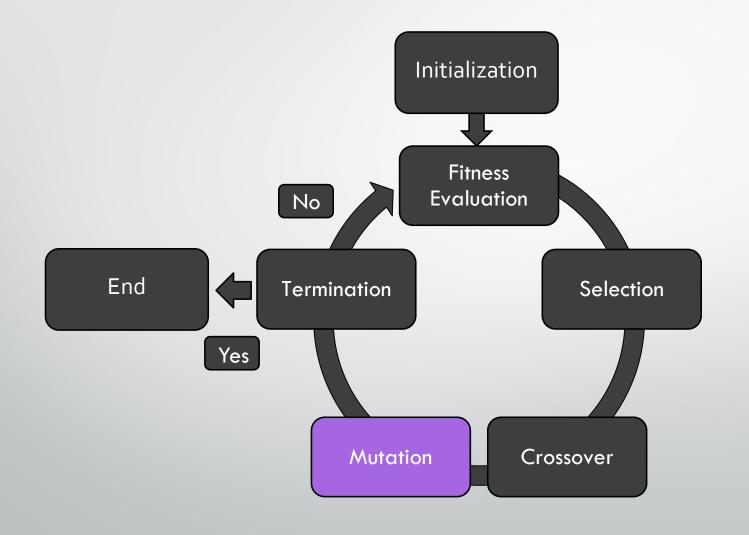


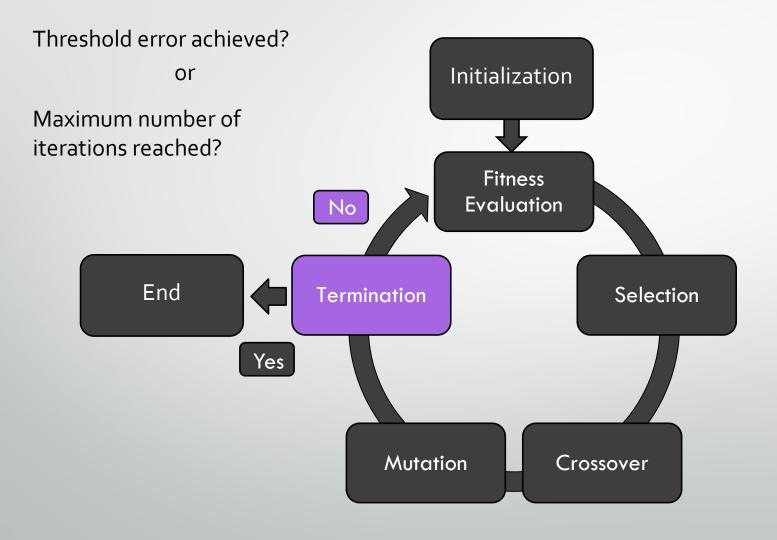


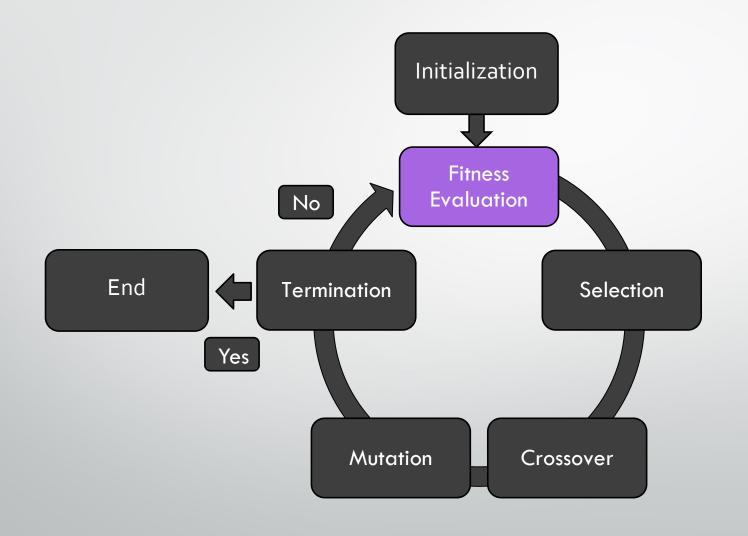


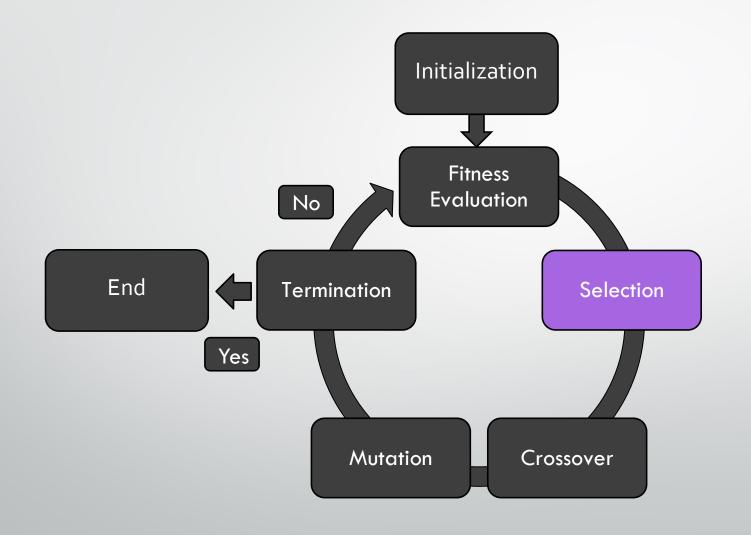


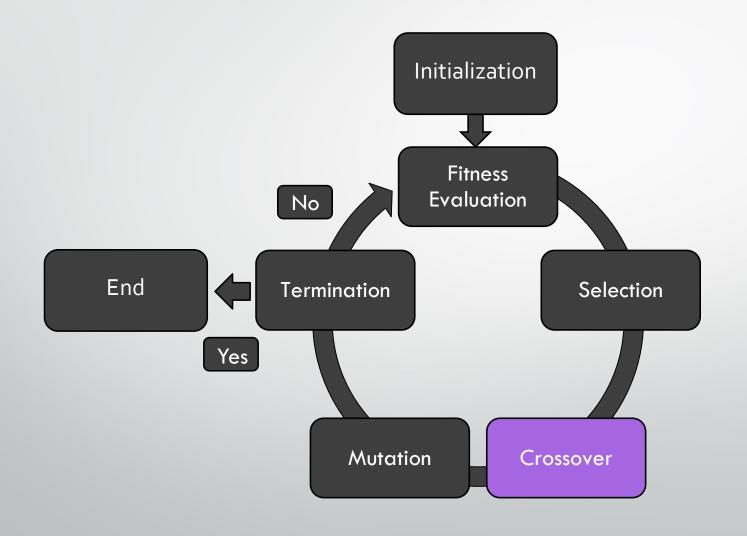


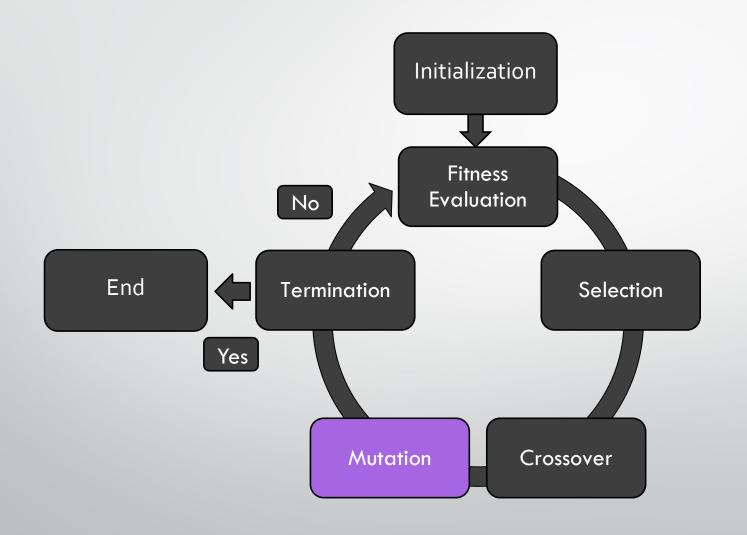


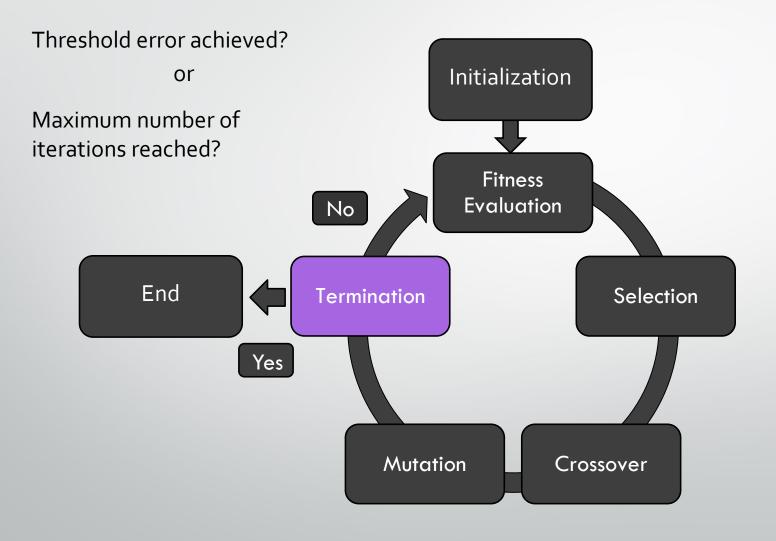


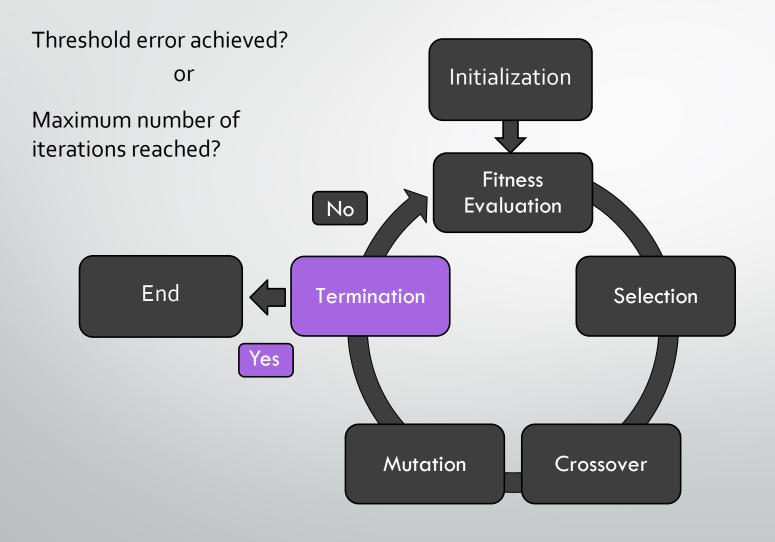


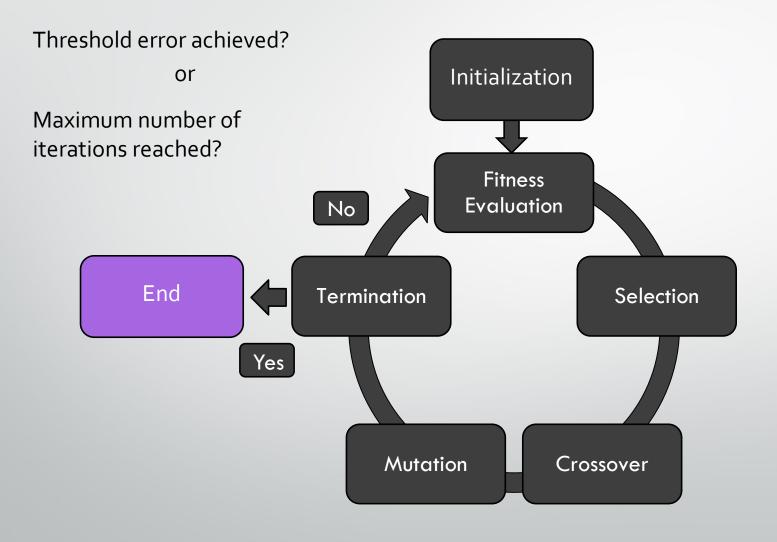












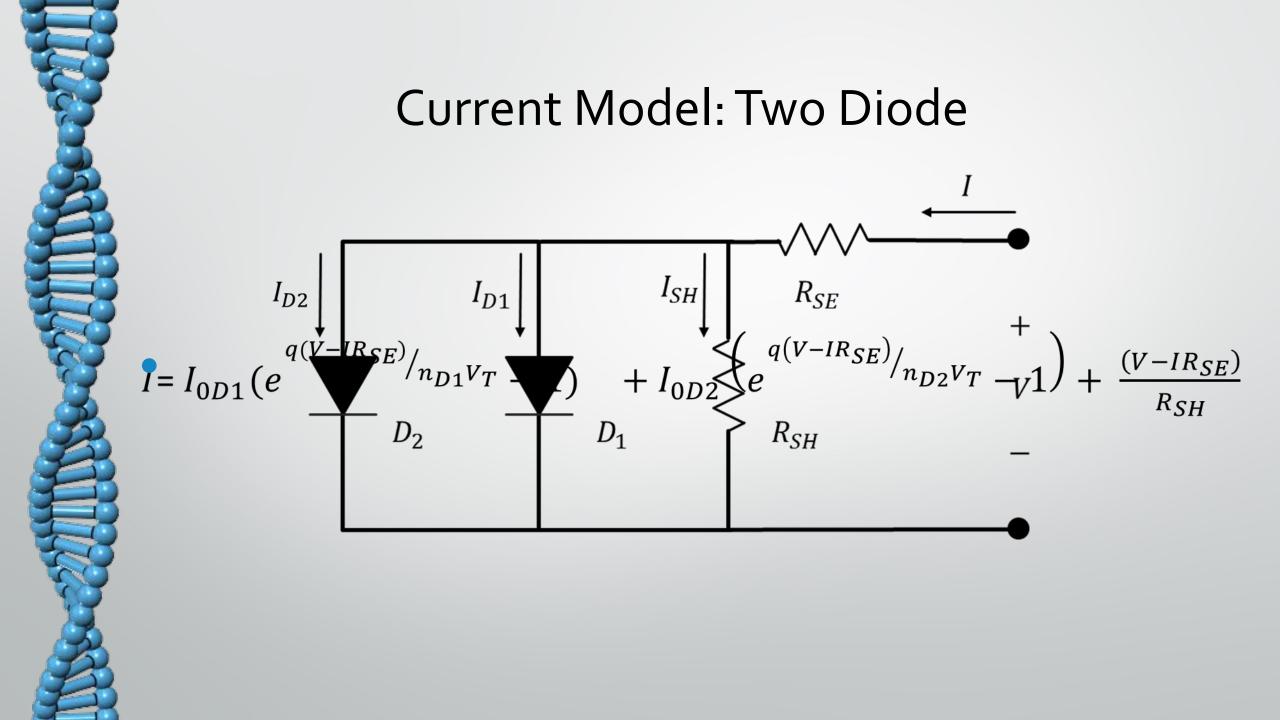
Applied Model

Two-Diode Model

Diode 1: SRH-diode

Diode 2: "Diode-like" shunt

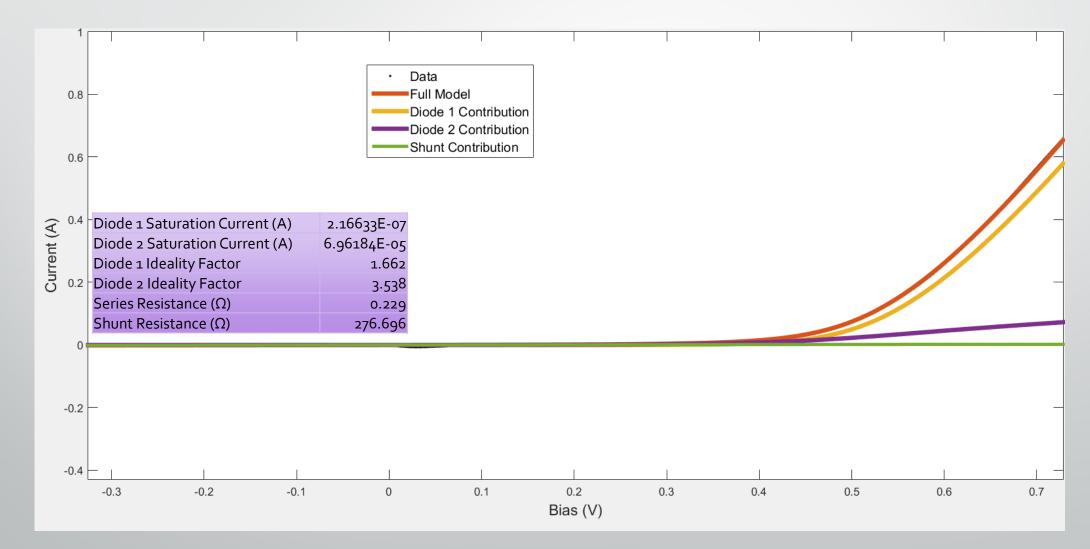
Shunt: Alternate current pathway



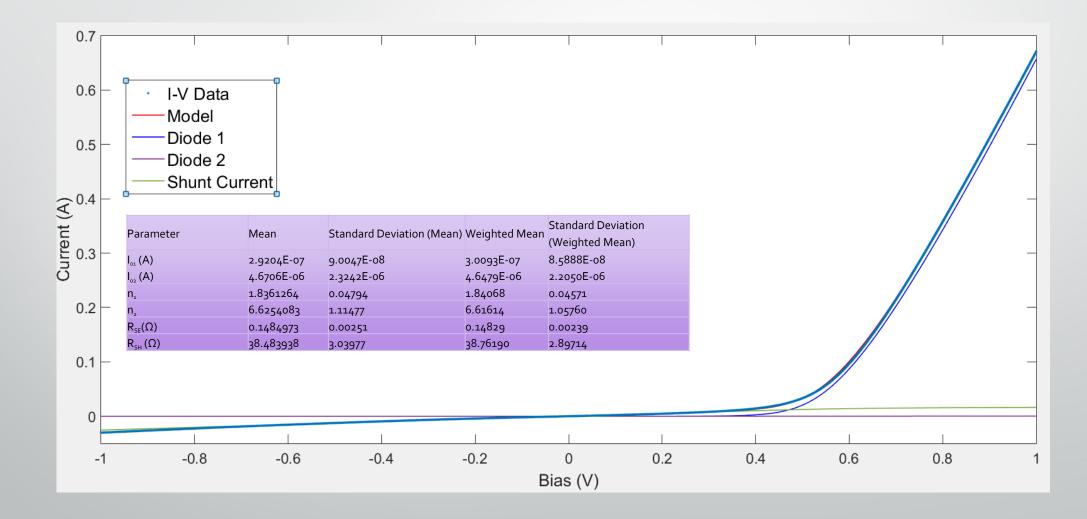
Current Model: Two Diode

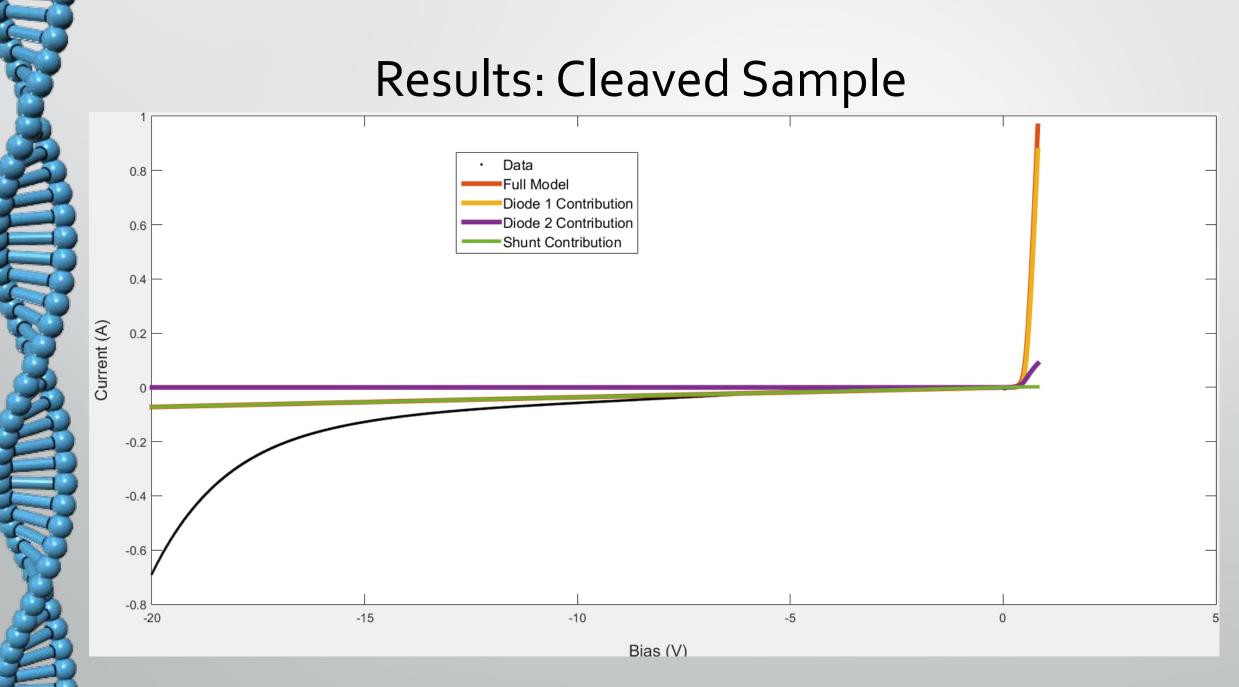
Parameter	interpretation
I_{0D1}	Dark saturation current of PN junction
<i>I</i> _{0D2}	Dark saturation current of "Diode-like" shunt
R_{SE}	Series resistance
R_{SH}	Shunt resistance
n_{D1}	Diode 1 ideality factor
n_{D2}	Diode 2 ideality factor

Results: Cleaved Sample

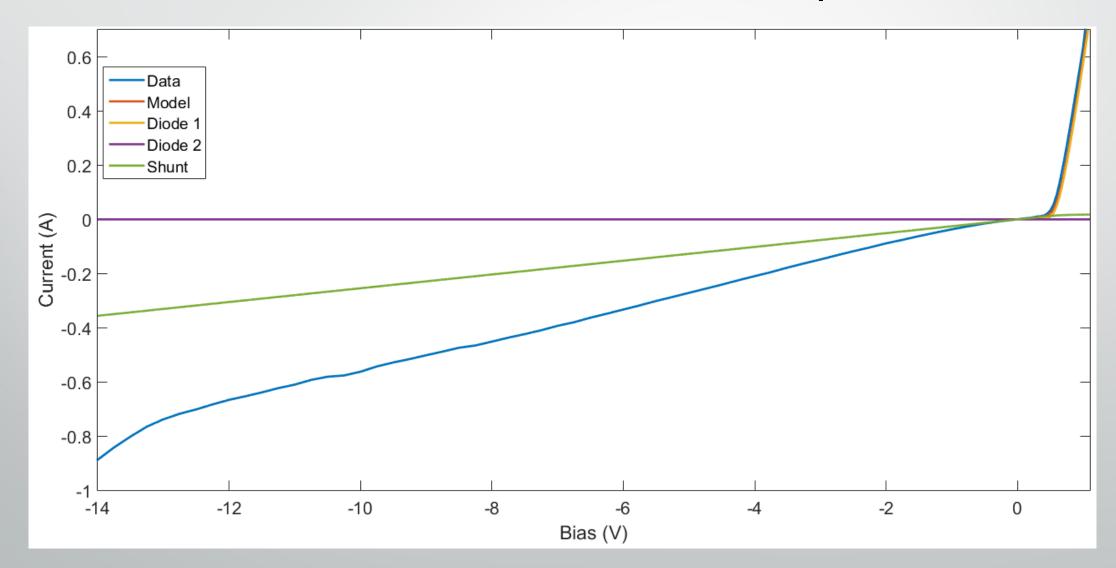


Results: Laser Scribed Sample





Results: Laser Scribed Sample



Proposed Model

Five-Diode Model

Diode 1: SRH-diode

Diode 2: "Diode-like" shunt

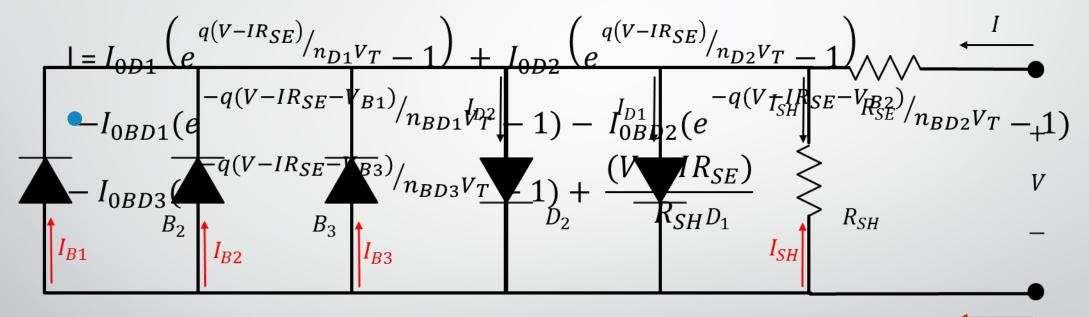
Shunt: Alternate current pathway

Breakdown diode 1: Type I breakdown – Pre-Breakdown

Breakdown diode 2: Type II breakdown — Trap assisted tunnelling

Breakdown diode 3: Type III breakdown – Avalanche breakdown

Current Model: Five Diode



Proposed Model: Five Diode

Parameter	interpretation
I _{0D1}	Dark saturation current of PN junction
I _{0D2}	Dark saturation current of "Diode-like" shunt
R_{SE}	Series resistance
R _{SH}	Shunt resistance
n_{D1}	Diode 1 ideality factor
n_{D2}	Diode 2 ideality factor
I _{0B1}	Dark Saturation current breakdown diode 1
<i>I</i> _{0<i>B</i>2}	Dark Saturation current breakdown diode 2
<i>I</i> _{0B3}	Dark Saturation current breakdown diode 3
n_{B1}	Breakdown diode 1: ideality factor
n_{B2}	Breakdown diode 2: ideality factor
n_{B3}	Breakdown diode 3: ideality factor
V_{B1}	Breakdown voltage – breakdown diode 1
V_{B2}	Breakdown voltage – breakdown diode 2
V _{B3}	Breakdown voltage – breakdown diode 3

Conclusion

Forward Bias

- Parameters of a mc-Si solar cells can be optimized using an Genetic Algorithm.
- Bulk response: Shockley-Reed-Hall model of recombination mechanism.
- Secondary diode response: likely due to defect recombination mechanisms.
- The remainder of the response is due to the contribution of the shunt current.

Reverse Bias

- Two-diode module is not appropriate
- Proposed five-diode model
 - Pre-breakdown
 - IFE- through trap assisted tunneling
 - Avalanche breakdown

Acknowledgements

